

# New p-type, near-infrared transparent conducting thin films with better performance

January 19 2022, by Zhang Nannan

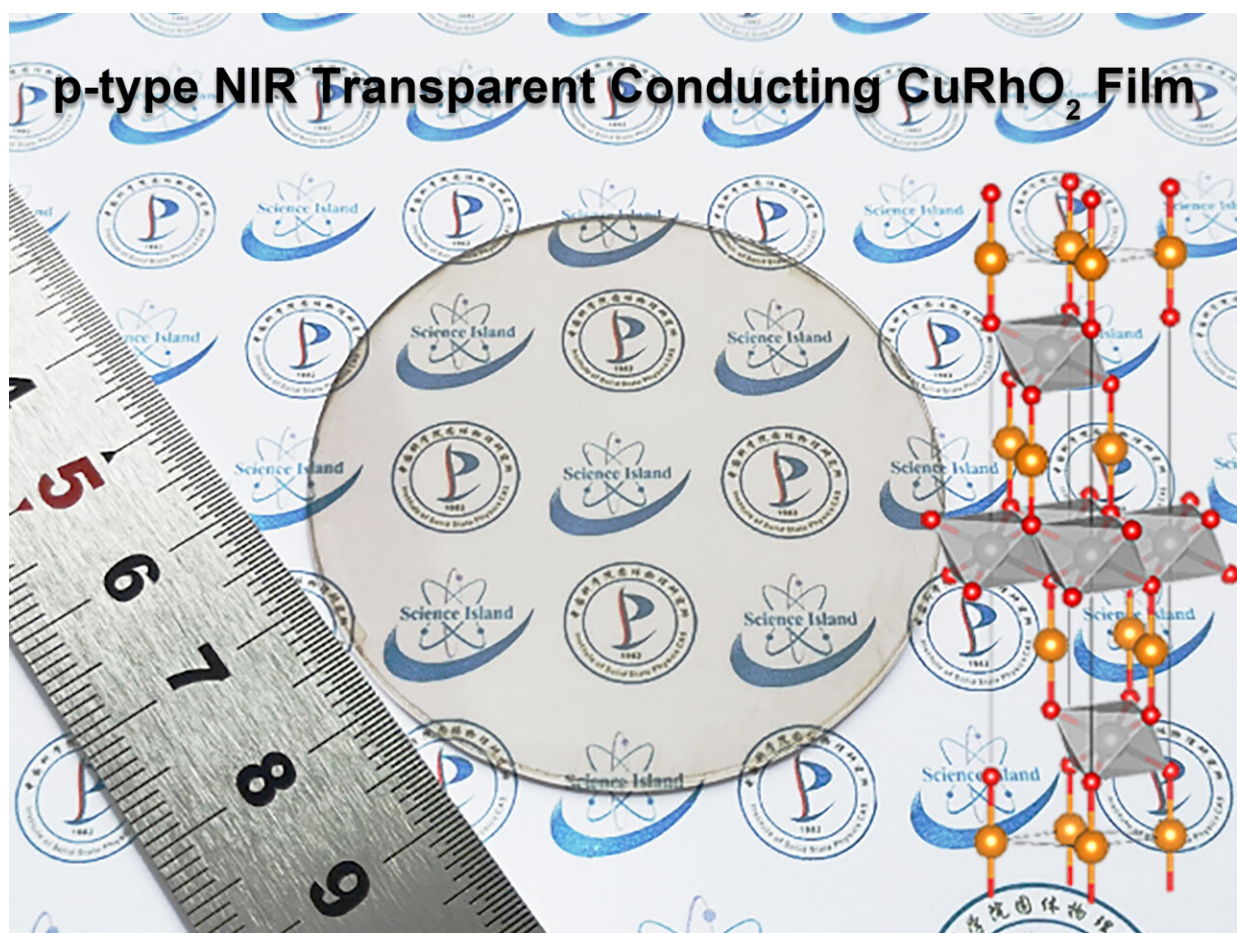


Fig. 1. Photo of p-type NIR TCCuRhO<sub>2</sub> thin film with 2 inches size. Credit: Wei Renhuai

A group of scientists at the Hefei Institutes of Physical Sciences of the Chinese Academy of Sciences has developed new p-type (positive hole) near infrared (NIR) transparent conducting (TC) films with ultra-high conductivity, unveiling a new material of TC.

"They have extraordinary properties," Wei Renhuai, a physicist who led the team, "the NIR optical transmittance of the films can reach as high as 85~60%, while maintaining the film resistance at room temperature at a low level."

In recent years, p-type TC has attracted extensive attention. Although n-type (negative electron) TC is common in current market, the incorporation of p-type TC and [n-type](#) TC can achieve invisible active circuit heterostructure.

Compared with traditional delafossite-based P-type TC, the room-temperature conductivity of this novel TC is much higher. In addition, the films also exhibit high near-infrared transmittance with a low [room-temperature](#) sheet resistance.

In the experiment, based on the first-principles calculations, the scientists found that  $\text{CuRhO}_2$  showed p-type conducting characteristics and processed a narrow indirect bandgap of 2.31 eV. Meanwhile, the optical absorption in the NIR and visible range is much low. The larger  $\text{Rh}^{3+}$  ionic radius makes the  $\text{CuRhO}_2$  accept hole-type carriers with high concentration.

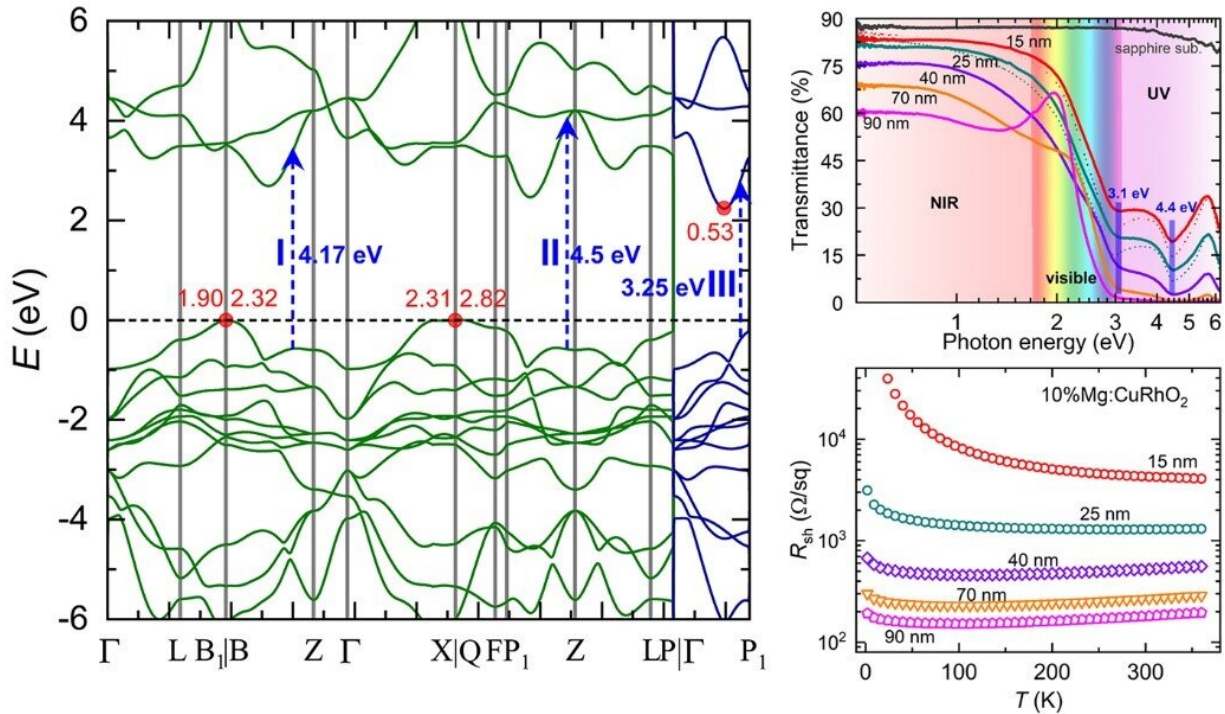


Fig. 2. Calculated electronic band structure for the CuRhO<sub>2</sub> (left). Optical transmittance and room-temperature sheet resistance for 10% Mg-doped CuRhO<sub>2</sub> thin films (right). Credit: Wei Renhuai

The great advance in [p-type](#) NIR TC CuRhO<sub>2</sub> thin films, based on both theoretical calculations and [experimental results](#), will significantly improve the development of future multifunctional invisible optoelectronic devices.

**More information:** Chenhui Li et al, p-Type Near-Infrared Transparent Delafossite Thin Films with Ultrahigh Conductivity, *Advanced Optical Materials* (2022). [DOI: 10.1002/adom.202102559](https://doi.org/10.1002/adom.202102559)

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